

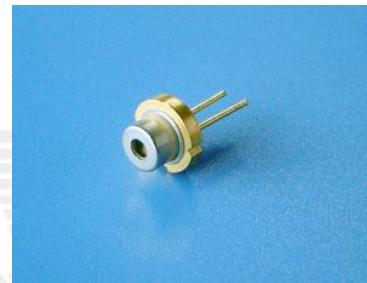


1550nm Laser Diode

CHANGCHUN NEW INDUSTRIES
OPTOELECTRONICS TECH.CO.,LTD.

■ Features

- Output Power: 20mW (CW)
- Efficient Quantum Well Structure
- Standard TO-18 Package



■ Absolute Maximum Ratings

(Tc=25°C)

Item	Symbol	Absolute Maximum Ratings	Unit
Optical Output Power	Po	20	mW
LD Reverse Voltage	Vr (LD)	2	V
Storage Temperature	Tstg	-40~85	°C
Operating Case Temperature	Tc	-40~40	°C

■ Initial Electrical/Optical Characteristics

(Tc=25°C)

Item	Symbol	Typ.	Unit
Optical Output	Po	20	mW
Peak Wavelength*	λp	1550±5	nm
Threshold Current	Ith	≤0. 03	A
Operating Current	Iop	≤0. 1	A
Slope Efficiency	η	≥0. 15	W/A
Operating Voltage	Vop	≤1. 8	V
Horizontal Beam Divergence	θ//	≤25	deg.
Vertical Beam Divergence	θ⊥	≤38	deg.
Spectrum FWHM		<0.3	
Wavelength Temperature Coefficient		0.2	nm/°C
Polarization		TE	

* Measuring specifications.

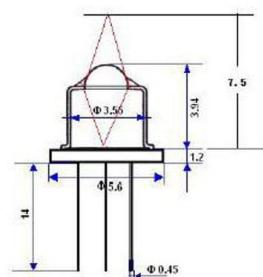
All figures in this specification are measured by CNI's method and may contain measurement deviations.

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The above specifications are for reference purpose only and subjected to change without prior notice.

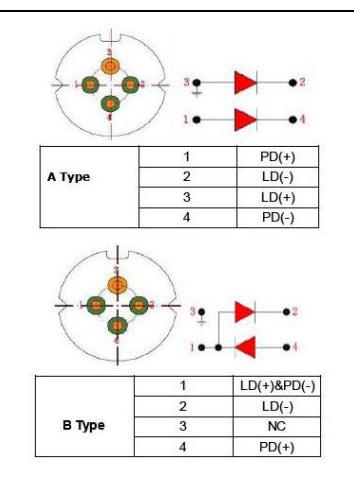
Outline Dimension

TO-18 Package



(Unit: mm)

Pin Connection



Changchun New Industries Optoelectronics Tech. Co., Ltd
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◆ CONTACT

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